



# PJA3434

## 20V N-Channel Enhancement Mode MOSFET

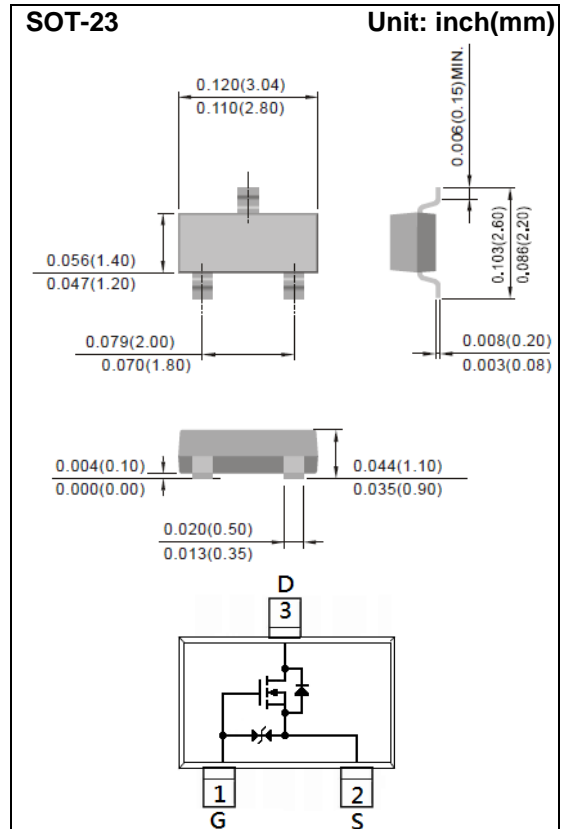
**Voltage** 20 V **Current** 750mA

### Features

- Low Voltage Drive (1.2V).
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc.
- ESD Protected
- Lead free in compliance with EU RoHS 2011/65/EU directive..
- Green molding compound as per IEC61249 Std. (Halogen Free)

### Mechanical Data

- Case: SOT-23 Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0003 ounces, 0.0084 grams
- Marking: A34



### Maximum Ratings and Thermal Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

| PARAMETER  | SYMBOL                            | LIMIT                | UNITS |
|--|-----------------------------------|----------------------|-------|
| Drain-Source Voltage                             | V <sub>DS</sub>                   | 20                   | V     |
| Gate-Source Voltage                              | V <sub>GS</sub>                   | ±10                  | V     |
| Continuous Drain Current                         | I <sub>D</sub>                    | 750                  | mA    |
| Pulsed Drain Current <sup>(Note 4)</sup>         | I <sub>DM</sub>                   | 1500                 | mA    |
| Power Dissipation                                | P <sub>D</sub>                    | T <sub>a</sub> =25°C | 500   |
|  |                                   | Derate above 25°C    | 4     |
| Operating Junction and Storage Temperature Range | T <sub>J</sub> , T <sub>STG</sub> | -55~150              | °C    |
| Typical Thermal resistance                       | R <sub>θJA</sub>                  | 250                  | °C/W  |
| - Junction to Ambient <sup>(Note 3)</sup>        |                                   |                      |       |



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## Electrical Characteristics ( $T_A=25^\circ\text{C}$ unless otherwise noted)

| PARAMETER   | SYMBOL       | TEST CONDITION  | MIN. | TYP.      | MAX.     | UNITS      |
|---|--------------|---|------|-----------|----------|------------|
| <b>Static</b>   |              |   |      |           |          |            |
| Drain-Source Breakdown Voltage                        | $BV_{DSS}$   | $V_{GS}=0V, I_D=250\mu A$   | 20   | -         | -        | V          |
| Gate Threshold Voltage                                | $V_{GS(th)}$ | $V_{DS}=V_{GS}, I_D=250\mu A$   | 0.3  | 0.65      | 1.0      | V          |
| Drain-Source On-State Resistance                      | $R_{DS(on)}$ | $V_{GS}=4.5V, I_D=600mA$  | -    | 280       | 400      | m $\Omega$ |
|   |              | $V_{GS}=2.5V, I_D=200mA$  | -    | 350       | 650      |            |
|   |              | $V_{GS}=1.8V, I_D=100mA$  | -    | 400       | 800      |            |
|   |              | $V_{GS}=1.5V, I_D=50mA$   | -    | 500       | 1200     |            |
|   |              | $V_{GS}=1.2V, I_D=20mA$   | -    | 1000      | 3000     |            |
| Zero Gate Voltage Drain Current                       | $I_{DSS}$    | $V_{DS}=16V, V_{GS}=0V$   | -    | 0.01      | 1        | $\mu A$    |
| Gate-Source Leakage Current                           | $I_{GSS}$    | $V_{GS}=\pm 8V, V_{DS}=0V$  | -    | $\pm 0.5$ | $\pm 10$ | $\mu A$    |
| <b>Dynamic</b> (Note 5)                               |              |   |      |           |          |            |
| Total Gate Charge                                     | $Q_g$        | $V_{DS}=10V, I_D=600mA,$<br>$V_{GS}=4.5V$ (Note 1,2)                    | -    | 1.4       | -        | nC         |
| Gate-Source Charge                                    | $Q_{gs}$     |   | -    | 0.22      | -        |            |
| Gate-Drain Charge                                     | $Q_{gd}$     |   | -    | 0.21      | -        |            |
| Input Capacitance                                     | $C_{iss}$    | $V_{DS}=10V, V_{GS}=0V,$<br>$f=1.0MHz$                                  | -    | 67        | -        | pF         |
| Output Capacitance                                    | $C_{oss}$    |   | -    | 19        | -        |            |
| Reverse Transfer Capacitance                          | $C_{rss}$    |   | -    | 6         | -        |            |
| Turn-On Delay Time                                    | $t_{d(on)}$  | $V_{DD}=10V, I_D=150mA,$<br>$V_{GS}=4.0V,$<br>$R_G=10\Omega$ (Note 1,2) | -    | 2.8       | -        | ns         |
| Turn-On Rise Time                                     | $t_r$        |   | -    | 20        | -        |            |
| Turn-Off Delay Time                                   | $t_{d(off)}$ |   | -    | 23        | -        |            |
| Turn-Off Fall Time                                    | $t_f$        |   | -    | 23        | -        |            |
| <b>Drain-Source Diode</b>                             |              |   |      |           |          |            |
| Maximum Continuous Drain-Source Diode Forward Current | $I_S$        | ---   | -    | -         | 0.5      | A          |
| Diode Forward Voltage                                 | $V_{SD}$     | $I_S=0.5A, V_{GS}=0V$   |      | 0.87      | 1.3      | V          |

**NOTES :**

1. Pulse width  $\leq 300\mu s$ , Duty cycle  $\leq 2\%$
2. Essentially independent of operating temperature typical characteristics.
3.  $R_{\theta JA}$  is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.
4. The maximum current rating is package limited.
5. Guaranteed by design, not subject to production testing.



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## TYPICAL CHARACTERISTIC CURVES

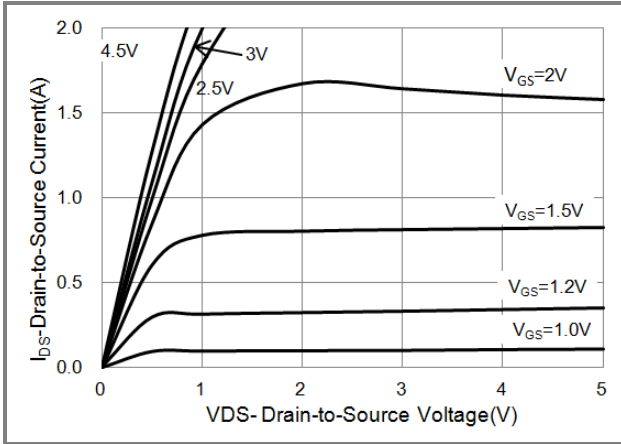


Fig.1 On-Region Characteristics

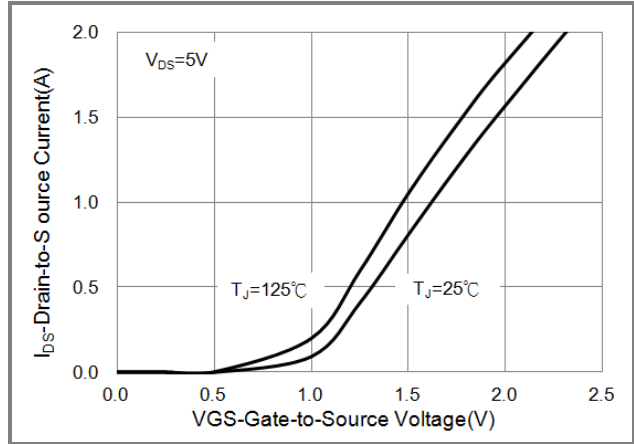


Fig.2 Transfer Characteristics

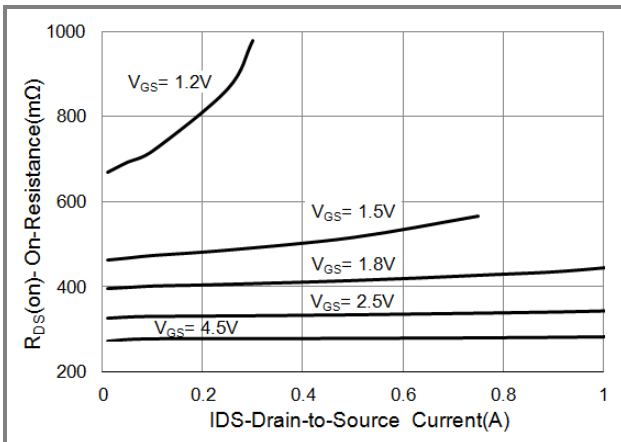


Fig.3 On-Resistance vs. Drain Current

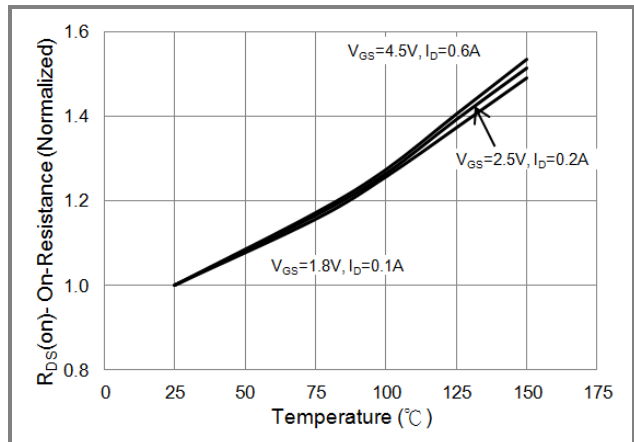


Fig.4 On-Resistance vs. Junction temperature

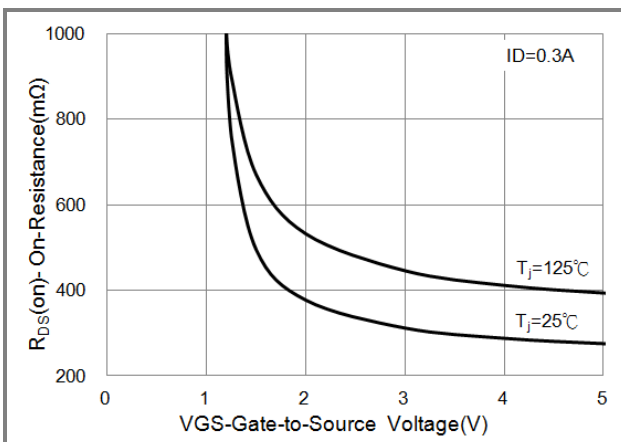


Fig.5 On-Resistance Variation with VGS.

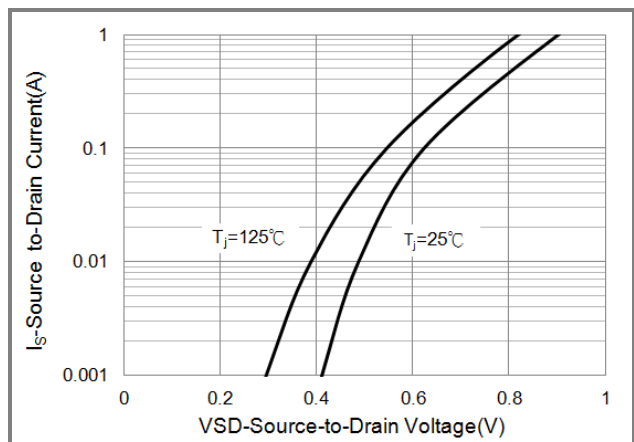


Fig.6 Body Diode Characteristics



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## TYPICAL CHARACTERISTIC CURVES

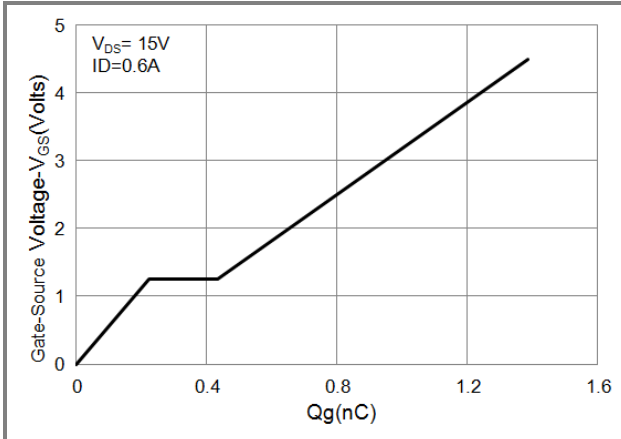


Fig.7 Gate-Charge Characteristics

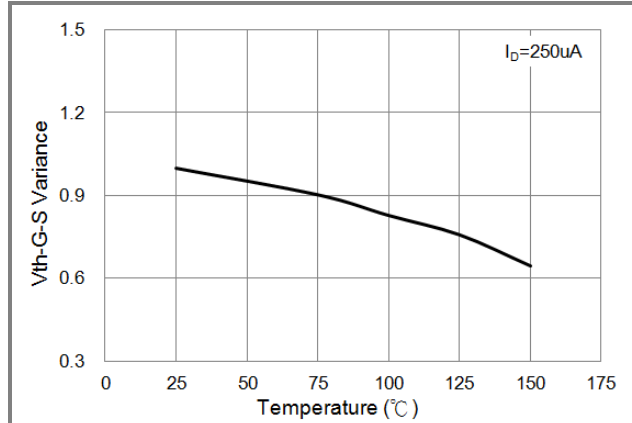


Fig.8 Threshold Voltage Variation with Temperature.

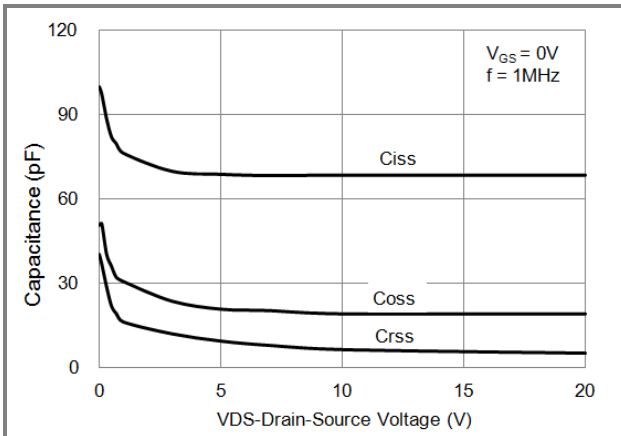


Fig.9 Capacitance vs. Drain-Source Voltage.

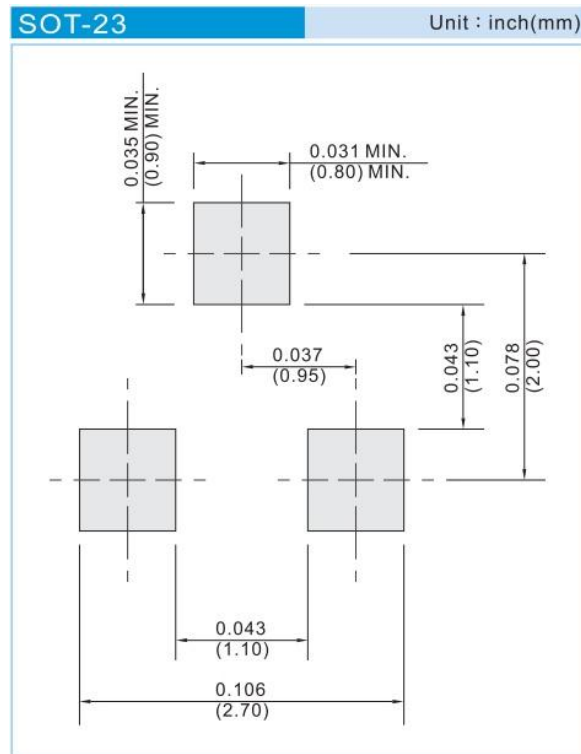


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## PART NO PACKING CODE VERSION

| PART NO PACKING CODE | Package Type | Packing type       | Marking | Version      |
|----------------------|--------------|--------------------|---------|--------------|
| PJA3434_R1_00001     | SOT-23       | 3K pcs / 7" reel   | A34     | Halogen free |
| PJA3434_R2_00001     | SOT-23       | 12K pcs / 13" reel | A34     | Halogen free |

## MOUNTING PAD LAYOUT





## PJA3434

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